

Electronic Surveillance and Security Applications of Magnetic Glass-coated Microwires

Valentina Zhukova, Mihail Ipatov, Paula Corte-León,
 Alvaro Gonzalez, Alfonso García- Gómez
 Dept Materials Physics, Dept. Applied Physics and EHU
 Quantum Center, Univ. Basque Country, UPV/EHU, 20018
 San Sebastian, Spain
 e-mails: valentina.zhukova@ehu.es; mihail.ipatov@ehu.es;
 paula.corte@ehu.es; alvaro.gonzalezv@ehu.es;
 alfonso.garciag@ehu.es

Arcady Zhukov
 Dept Materials Physics, Dept. Applied Physics and EHU
 Quantum Center, Univ. Basque Country, UPV/EHU, 20018
 San Sebastian and Ikerbasque, Bulbao, Spain
 e-mail: arkadi.joukov@ehu.es

Abstract—Applications in security and electronic surveillance require a combination of excellent magnetic softness with good mechanical and anti-corrosive properties and low dimensionality. We overviewed the feasibility of using glass-coated microwires for electronic article surveillance and security applications, as well as different routes of tuning the magnetic properties of individual microwires or microwires arrays making them quite attractive for electronic article surveillance and security applications. We provide the routes for tuning the hysteresis loops non-linearity by the magnetostatic interaction between the microwires in the arrays of different types of amorphous microwires. The presence of neighboring microwire (either Fe or Co-based) significantly affects the hysteresis loop of the whole microwires array. In a microwires array containing magnetically bistable microwires, we observed splitting of the initially rectangular hysteresis loop with a number of Barkhausen jumps correlated with the number of magnetically bistable microwires. Essentially, non-linear and irregular hysteresis loops have been observed in mixed arrays containing Fe and Co-rich microwires. The obtained non-linearity in hysteresis loops allowed to increase the harmonics and tune their magnetic field dependencies. On the other hand, several routes allowing to tune the switching field by either post-processing or modifying the magnetoelastic anisotropy have been reviewed. The observed unique combination of magnetic properties together with thin dimensions and excellent mechanical and anti-corrosive properties provide excellent perspectives for the use of glass-coated microwires for security and electronic surveillance applications.

Keywords- magnetic microwires; magnetic softness; magnetic bistability, magnetic tags.

I. INTRODUCTION

Soft magnetic materials are highly demanded by several industries, including (but not limited to) microelectronics, electrical engineering, car, aerospace and aircraft industries, medicine, magnetic refrigerators, home entertainment, energy harvesting and conversion, informatics, magnetic recording or security and electronic surveillance [1]-[2]. In

most cases, like the case of security and electronic surveillance, in addition to excellent magnetic softness, a combination of mechanical and anti-corrosive properties and low dimensionality is required [3].

Almost all department stores, supermarkets, airports, libraries, museums, etc. are provided with different types of security and anti-theft systems. The principle of Electronic Article Surveillance (EAS) systems operation is well established: articles are provided with tags that respond to electromagnetic fields generated by the gates at the store/supermarket/library exits [3]. The response is picked up by the antenna installed on the gate, switching on the alarm. It is estimated that hundreds of thousands of such EAS systems have been installed and millions of tags are produced daily. Considering the great number of tags, they must be small, robust enough and inexpensive. Additionally, the magnetic materials employed in tags must be magnetically soft enough. The magnetic softness of crystalline soft magnetic materials (Permalloy, Fe-Si) is affected by processing. Therefore, amorphous soft magnetic materials, prepared by rapid melt quenching are considered as among the most suitable materials for tags containing soft magnetic materials [3][4].

Indeed, as a rule, amorphous materials present excellent magnetic softness together with superior mechanical properties [3]-[6]. Abrupt deterioration of the mechanical properties (such as tensile yield) upon the devitrification of amorphous precursor is reported [6]. Additionally, the fabrication process of amorphous materials involving rapid melt quenching is fast and inexpensive [1]-[7]. Accordingly, amorphous soft magnetic materials are useful for the design of robust magnetic devices and magnetoelastic sensors [8]-[12].

As discussed elsewhere, soft magnetic materials with squared hysteresis loops and relatively low coercivities are the preferred candidates for the EAS systems using magnetic tags [3]. The rectangular hysteresis loops can be easily implemented in different families of amorphous magnetic wires [4]. Therefore, considerable attention has

been paid to applications of amorphous wires for magnetic tags for different kinds of EAS systems [4].

The aforementioned squared hysteresis loops of magnetic wires are linked to the peculiar remagnetization process of magnetic wires running through a single and large Barkhausen jump [4] [14].

Glass-coated magnetic microwires prepared by the so-called Taylor-Ulitovsky technique present the widest metallic nucleus diameters range (from 200 nm up to 100 μm) [4][15][16]. In this way, the Taylor-Ulitovsky method is the unique technique allowing fabrication of nanowires by rapid melt quenching [15]. On the other hand, the preparation of amorphous magnetic wires with diameter of about 100 μm coated by glass has recently been reported [16]. The presence of a flexible, thin, bio-compatible and insulating glass coating allows to enhance the corrosive resistance and, therefore, makes these microwires suitable for novel applications including biomedicine, electronic article surveillance, non-destructive monitoring external stimuli (stresses, temperature) in smart composites or construction health monitoring through the microwire inclusions [17][18].

Accordingly, considering dimensionality and combination of physical properties (magnetic, mechanical, corrosive), amorphous soft magnetic microwires are potentially suitable materials for electronic article surveillance and security applications [4][19][20]. There are several original papers dealing with rather different (multi-bit or single-bit) security and EAS applications of magnetic microwires [19][20]. In this paper, we will provide an overview of the trends related to EAS and security applications of glass-coated magnetic microwires.

This paper is organized as follows. In Section 2, the experimental methods as well as the microwires characteristics analyzed in this paper are provided. Section 3 deals with results on the feasibility of using magnetic microwires for magnetic tags followed by an overview of tuning of hysteresis loop non-linearity by the magnetostatic interaction between microwires.

II. EXPERIMENTAL SYSTEM DETAILS

Generally, we analyzed two different types of magnetic amorphous microwires: i) amorphous microwires with high positive magnetostriction coefficients, λ_s , (Fe-Si-B-C, Fe-Ni-Si-B-C or Fe-Ni-Si-B) and ii) amorphous microwires with vanishing λ_s (Co-Fe-Ni-B-Si-Mo, Co-Fe-Ni-B-Si-Mo, Co-Fe-B-Si-Cr-Ni or Co-Fe-B-Si-C). We studied microwires with metallic nucleus diameters, d , ranging from 10 up to 100 μm prepared using the Taylor-Ulitovsky method described elsewhere [4][21]. The Taylor-Ulitovsky method allows preparation of thinnest metallic wires (with typical diameters of the order of 0.1 to 100 μm) covered by an insulating glass coating [5][21].

The amorphous structure of all the microwires has been proved by the X-ray Diffraction (XRD) method. Typically,

the crystallization of amorphous microwires was observed at $T_{\text{ann}} \geq 500^\circ \text{C}$ [4].

The induction method has previously been used for the hysteresis loops measurements. The details of the experimental set-up are described elsewhere [22]. The hysteresis loops were represented as the magnetic field, H , dependence of the normalized magnetization, M/M_0 , being M - the magnetic moment at a given magnetic field, and M_0 the magnetic moment at the maximum magnetic field amplitude H_m . Such hysteresis loops are useful for comparison of the samples with different chemical compositions (and, hence, different saturation magnetization).

In several cases, the hysteresis loops were measured with a conventional Super-conducting Quantum Interference Device (SQUID).

III. EXPERIMENTAL RESULTS AND DISCUSSION

Magnetic tags applications require a non-linear hysteresis loop that contains the characteristic distribution of harmonic frequencies. It is believed that the steeper the magnetization reversal, the higher the harmonic content of the signal. Accordingly, perfectly rectangular hysteresis loops with low coercivity observed in Fe-rich microwires (Figure 1) are attractive for use as magnetic tags.

On the other hand, the non-linearity of the hysteresis loop of the magnetic microwires can be further improved using the magnetostatic interaction of microwires. Below, we will present several experimental results on magnetic response of two kinds of individual microwires ($\text{Co}_{67}\text{Fe}_{3.9}\text{Ni}_{1.5}\text{B}_{11.5}\text{Si}_{14.5}\text{M}_{0.6}$ and $\text{Fe}_{74}\text{B}_{13}\text{Si}_{11}\text{C}_2$) as well as the arrays containing either microwires of the same type or arrays containing two different kinds of microwires.

The hysteresis loops of such microwires are rather different: $\text{Fe}_{74}\text{B}_{13}\text{Si}_{11}\text{C}_2$ microwire with high and positive magnetostriction coefficient, λ_s , exhibits perfectly rectangular hysteresis loops with $H_c \approx 100 \text{ A/m}$ (Figure 1a), while an inclined hysteresis loop with quite low H_c ($H_c \approx 5 \text{ A/m}$) is observed in $\text{Co}_{67}\text{Fe}_{3.9}\text{Ni}_{1.5}\text{B}_{11.5}\text{Si}_{14.5}\text{M}_{0.6}$ microwire (see Figure 2b).

The hysteresis loop of an array containing two $\text{Fe}_{74}\text{B}_{13}\text{Si}_{11}\text{C}_2$ microwires is rather different from that of a single $\text{Fe}_{74}\text{B}_{13}\text{Si}_{11}\text{C}_2$ microwire. Two Barkhausen jumps can be observed at magnetic field amplitude, $H_0 > 80 \text{ A/m}$ (see Figure 3a). Such peculiar hysteresis loop shape has been explained considering the magnetostatic interaction in the two-microwire array [4]. Such magnetostatic interaction is a consequence of stray fields created by magnetically bistable microwires: the superposition of external and stray fields causes magnetization reversal in one of the samples, when the external field is below the switching field of a single microwire. A single rectangular hysteresis loop (similar to the case of single microwire shown in Figure 1) is observed for $60 \text{ A/m} < H_0 < 80 \text{ A/m}$ (see Figure 3b).

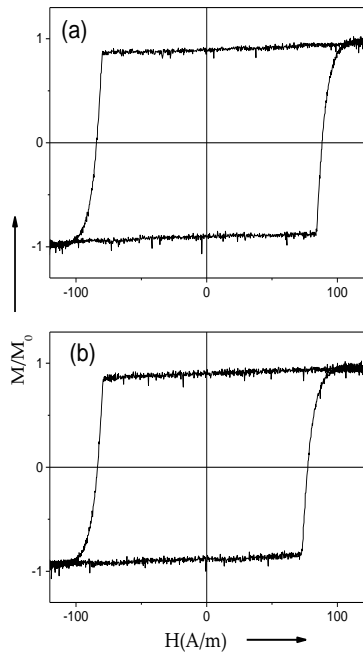


Figure 1. Hysteresis loops of as- prepared (a), and annealed at $T_{ann}= 400$ °C for 180 min (b) $Fe_{75}B_9Si_{12}C_4$ microwires.

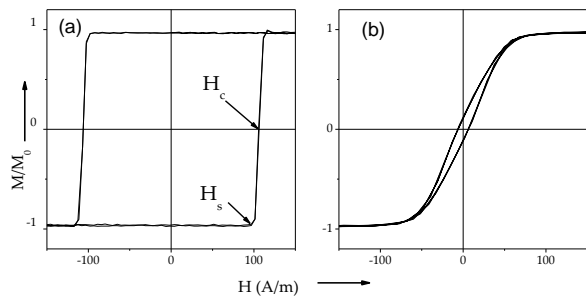


Figure 2. Hysteresis loops of $Fe_{75}B_9Si_{12}C_4$ microwires with positive (a) and $Co_{67}Fe_{3.9}Ni_{1.5}B_{11.5}Si_{14.5}M_{0.6}$ with vanishing (b) magnetostriction coefficients.

Increasing the magnetic field amplitude (approximately at $H_0 > 250$ A/m), this splitting of the hysteresis loop disappears (Figure 3b). Such dependence of the hysteresis loop of two microwires array can be understood from the counterbalance between the dH/dt and the switching time determined by the velocity of the DW propagation along the whole wire [4].

As discussed elsewhere [4], coercivity, H_c , is also affected by the frequency, f . Accordingly, H_c , as well as overall hysteresis loops of two microwires array, are affected by f in a similar way as by H_0 (see Figure 3b). For a two microwires array, two-steps hysteresis loops are observed for $f < 150$ Hz. At $f > 150$ Hz, the hysteresis loop splitting disappears, and at $150 < f < 1000$ Hz, a single smooth magnetization jump is observed.

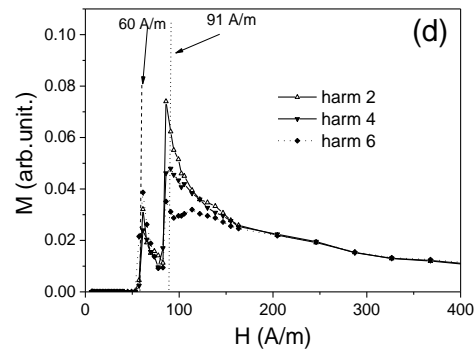
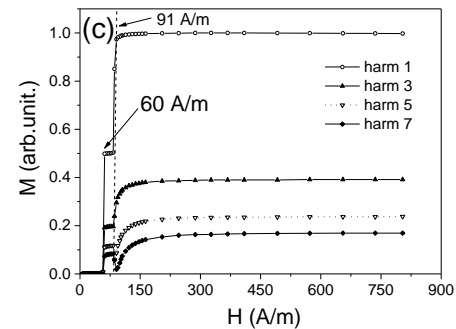
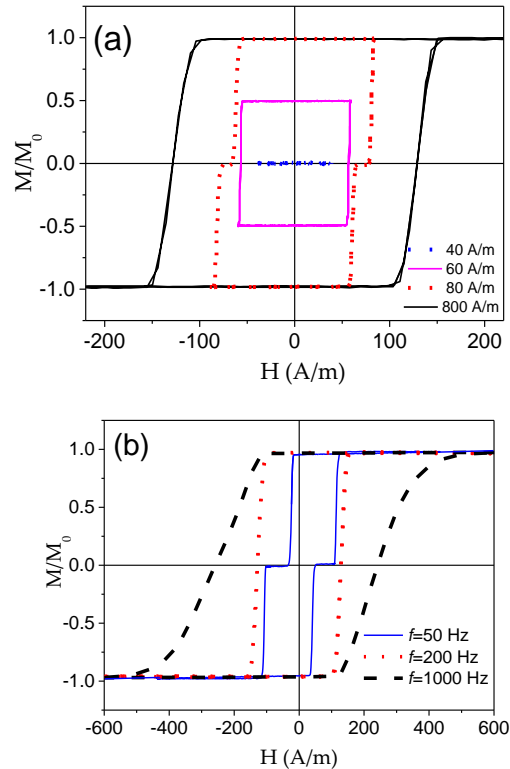


Figure 3. Hysteresis loops measured at different magnetic field amplitudes H_0 (a) and at different magnetic field frequencies f (b) for as array with two $Fe_{75}B_9Si_{12}C_4$ microwires, dependences of odd harmonics (c) and even harmonics (d) on magnetic field amplitude in linear array of two $Fe_{74}B_{13}Si_{11}C_2$ microwires.

Accordingly, the odd and even harmonics of the signal of two Fe-rich microwires array are affected by H_0 and f (see Figure 3c,d).

A sharp increase in the harmonics amplitudes is observed when H_0 exceeds H_c (see Figures 3c,d). The even harmonics amplitudes are significantly inferior to the odd harmonics amplitudes. The field dependences of odd harmonics have a "plateau" between 60 and 90 A/m, which reflects the hysteresis loops splitting (see Figure 3a).

Another example of tuning the non-linearity of hysteresis loops and harmonics is the magnetostatic interaction of microwires with different character of hysteresis loops. Rather non-linear hysteresis loops can be obtained in an array consisting of one $\text{Co}_{67}\text{Fe}_{3.9}\text{Ni}_{1.5}\text{B}_{11.5}\text{Si}_{14.5}\text{M}_{0.6}$ and one $\text{Fe}_{74}\text{B}_{13}\text{Si}_{11}\text{C}_2$ microwires (see Figure 4a). In such array, at $H_0 < 90$ A/m (which corresponds to H_c of $\text{Fe}_{74}\text{B}_{13}\text{Si}_{11}\text{C}_2$ microwire) the hysteresis loops character is typical of those for a single $\text{Co}_{67}\text{Fe}_{3.9}\text{Ni}_{1.5}\text{B}_{11.5}\text{Si}_{14.5}\text{M}_{0.6}$ microwire. Essentially, non-linear hysteresis loops have been observed at $H_0 > 110$ A/m (Figure 4a). Such peculiar hysteresis loops can be interpreted as the superposition of two hysteresis loops: one from magnetically bistable $\text{Fe}_{74}\text{B}_{13}\text{Si}_{11}\text{C}_2$ microwire (shown in Figure 2a) and the other one from $\text{Co}_{67}\text{Fe}_{3.9}\text{Ni}_{1.5}\text{B}_{11.5}\text{Si}_{14.5}\text{M}_{0.6}$ microwire with linear hysteresis loop (shown in Figure 2b).

The peculiar hysteresis loop character at $H_0 \leq 120$ A/m can be explained by the partial magnetization reversal of the magnetically bistable wire under the influence of the stray field from the Co-based wire. The stray field is affected by the sample demagnetizing factor and the sample magnetization [23] [24]. In the case of Co-rich microwire the magnetization and hence, the stray field are affected by the applied magnetic field (as can be appreciated from the hysteresis loops shown in Figure 2b). In contrast, the magnetization of Fe-rich sample change by abrupt jump and below and above H_c is almost independent of the magnetic field (see Figure 2a).

Accordingly, such microwire array consisting of two microwires (Fe-rich and Co-rich) with different hysteresis loops presents odd and even harmonics quite different from the case of the array with two Fe-rich microwires (see Figures 4 b,c). A single sharp jump of odd and even harmonics is observed at $H_0 \approx H_c$. There is also a change in the odd and even harmonics in the weak ($H_0 < H_c$) field region (see Figures 4 b, c).

Thus, the use of arrays consisting of magnetic microwires allows us to create a complex and unique spectrum of magnetic harmonics in magnetic microwires.

Essentially, non-linear and irregular hysteresis loops have been observed in mixed arrays containing Fe and Co-rich microwires. The observed non-linear hysteresis loops allowed to increase the harmonics and to tune their magnetic field dependencies.

The aforementioned examples provide the routes for optimization of the response of magnetic microwires by

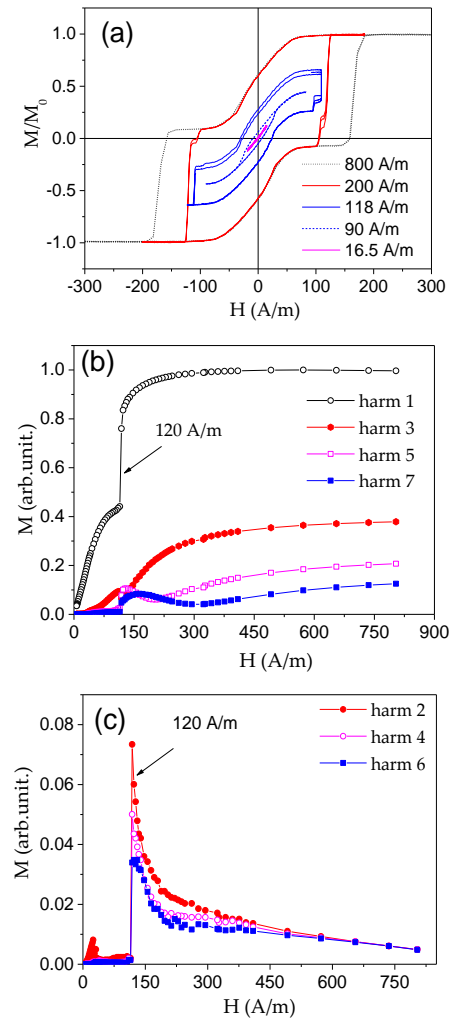


Figure 4. (a) Hysteresis loops of the $\text{Fe}_{74}\text{B}_{13}\text{Si}_{11}\text{C}_2 + \text{Co}_{67}\text{Fe}_{3.9}\text{Ni}_{1.5}\text{B}_{11.5}\text{Si}_{14.5}\text{M}_{0.6}$ array; (b) dependences of odd harmonics on magnetic field amplitude and (c) dependences of even harmonics on magnetic field amplitude. Reprinted with permission from ref. (4).

tuning the non-linearity of the hysteresis loops through the magnetostatic interaction. Such magnetic microwires can easily be incorporated into magnetic tags capable to respond to magnetic fields generated by the gates at the store/supermarket/library exits.

IV. CONCLUSIONS

In this paper, we showed that the presence of a neighbouring microwire (either Fe- or Co-based) significantly affects the hysteresis loop of the whole microwires array. In a microwires array containing magnetically bistable microwires, we observed splitting of the initially rectangular hysteresis loop with a number of Barkhausen jumps correlated with the number of magnetically bistable microwires. Essentially, non-linear and irregular hysteresis loops have been observed in mixed

arrays containing Fe and Co-rich microwires. The observed non-linear hysteresis loops allowed to increase the harmonics and to tune their magnetic field dependencies.

The observed unique combination of magnetic properties, together with thin dimensions and excellent mechanical and anti-corrosive properties, provide excellent perspectives for the use of glass-coated microwires for security and electronic surveillance applications.

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